## UNIVERSITY OF SWAZILAND FACULTY OF SCIENCE AND ENGINEERING DEPARTMENT OF PHYSICS

## MAIN EXAMINATION, DECEMBER 2019

TITLE OF PAPER

: ELECTRONICS 1

COURSE NUMBER : PHY 311

TIME ALLOWED

: THREE HOURS

INSTRUCTIONS

: Answer FOUR (4) questions only.

: Each question carries 25 Marks

Marks for different sections are shown

in far right margin.

THIS PAPER HAS 6 PAGES, INCLUDING THIS ONE.

DO NOT OPEN THE PAPER UNTIL PERMISSION IS GRANTED BY THE INVIGILATOR.

- 1. (a) Define the following
  - (i) Intrinsic semiconductor [1]
  - (ii) Doping [1]
  - (iii) pn-junction. [1]
  - (b) Sketch a bridge rectifier and the output (without a smoothening capacitor) and explain how it works. [5]
  - (c) Assume that a smoothening capacitor C was connected across the load resistor of the bridge rectifier. With the aid of a schematic diagram of the variation of the output signal with time, show that the ripple voltage,  $V_r$  can be written as

$$V_r = \frac{I_{av}}{2fC},$$

where  $I_{av}$  is the d.c. current and f is the frequency.

- (d) Modify the bridge circuit in (b) above to obtain a voltage doubler circuit and sketch the output signal if the input is sinusoidal. [4]
- (e) Consider the circuit in Figure 1 .
  - (i) Using the Zener diode model, obtain the load line equation for the circuit. [4]
  - (ii) Sketch the I-V characteristics of the diode together with the load line. [2]

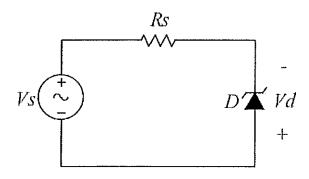


Figure 1

- 2. (a) Sketch and label typical drain and transfer characteristics of an n-channel JFET. [4]
  - (b) Write the equation for JFET transfer characteristic curve. [2]
  - (c) When the gate-source voltage,  $V_{GS}$  of a JFET is kept constant, a change in the drain-source voltage of 2 V leads to a corresponding change in the drain current of 0.5 mA. Use this information to calculate the drain resistance,  $r_d$  of the JFET. [5]
  - (d) The circuit in Fig. 2 represents a common-source amplifier. Assume  $I_{\rm DSS}=770~\mu A$  and  $V_{\rm GS(off)}=-3~\rm V.$

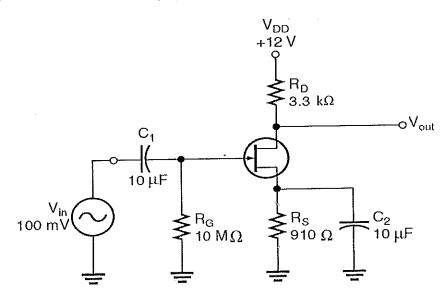


Figure 2: Common Source Amplifier

Calculate the following;

i. the drain current,  $I_{\rm D}$  [5] ii. the drain voltage  $V_{\rm D}$  [2] iii. the transconductance,  $g_{\rm m}$  [4] iv. the total output voltage of the amplifier. [3]

- 3. (a) With the aid of a circuit diagram, explain how a full-wave rectifier that utilises a center-tap transformer works. Sketch the output of the rectifier with reference to the transformer secondary voltage. [9]
  - (b) A bridge rectifier with a smoothing capacitor operates from 60 Hz. A load resistance of 1 k $\Omega$  is connected across the output terminals. The peak value of the output voltage is 24 V and the ripple voltage is 4 V.
    - (i) Sketch a graph of the output voltage against time with reference to the secondary voltage and label both axes. [4]
    - (ii) Determine the capacitance of the capacitor. [6]
  - (c) Fig.3 shows a half-wave rectifier with a smoothing capacitor. The average current through the load resistance is 10 mA. A period of oscillation of the secondary voltage is 20 ms and amplitude is 50 V. Calculate the average voltage across the load resistor. [6]

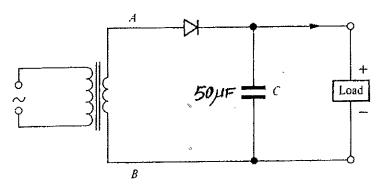


Figure 3

(a) Determine the Q-point for the circuit below and find the maximum peak value of base current for linear operation. Assume  $\beta_{DC}=200$ . [7]

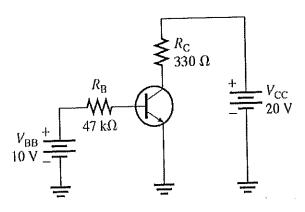


Figure 4: Bass -bias

(b) Consider the common-emitter amplifier shown in Figure 5,

- [5](i) perform the dc analysis of the circuit.
- [10](ii) perform ac analysis of the circuit. [3]
- (iii) Draw the waveforms.

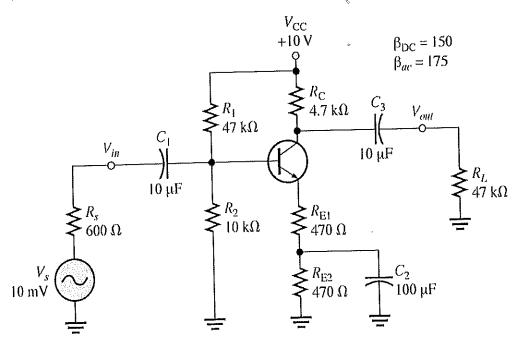


Figure 5: CE-Amplifier with  $R_L$ 

- 5. (a) Define the hybrid parameters of the transistor in terms of the d.c. currents and voltages . [2]
  - (b) Describe how you would determine the hybrid parameters of a bipolar transistor from the input and output characteristics of the transistor. [6]
  - (c) With reference to the circuit diagram in Fig.6, calculate the values of the dc voltages  $V_B$ ,  $V_C$  and  $V_{CE}$  and the direct currents  $I_B$  and  $I_E$ . Assume that the current  $I_{BB}$  flowing into the potential divider  $(R_1 \text{ and } R_2)$  is much greater than  $I_B$  and  $V_{BE} = 0.6$  V and  $h_{FE} = 200$ . [15]

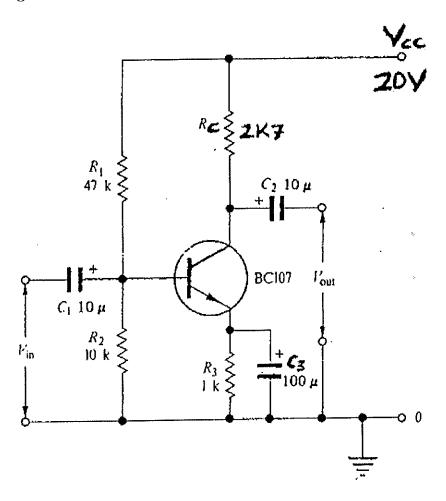


Figure 6

(d) (c) State the relation between pinch-off voltage,  $V_{\rm P}$ , and cutoff voltage,  $V_{\rm GS(off)}$ . [2]